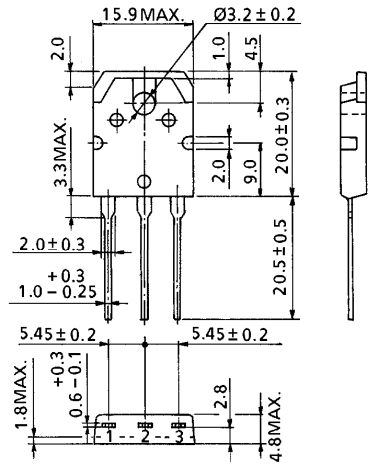
TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

2SA1962

POWER AMPLIFIER APPLICATIONS

Unit in mm

- High Collector Voltage : $V_{CEO} = -230V$ (Min.)
- Complementary to 2SC5242
- Recommend for 80W High Fidelity Audio Frequency Amplifier Output Stage.



1. BASE
2. COLLECTOR (HEAT SINK)
3. EMITTER

JEDEC	—
EIAJ	—
TOSHIBA	2-16C1A

Weight : 4.7g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

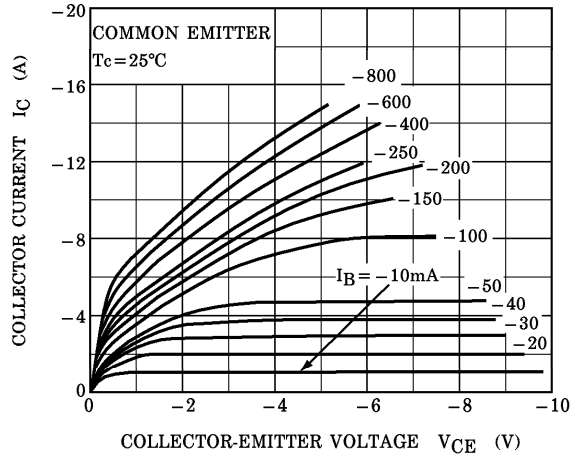
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	−230	V
Collector-Emitter Voltage	V_{CEO}	−230	V
Emitter-Base Voltage	V_{EBO}	−5	V
Collector Current	I_C	−15	A
Base Current	I_B	−1.5	A
Collector Power Dissipation (Tc = 25°C)	P_C	130	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55~150	°C

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

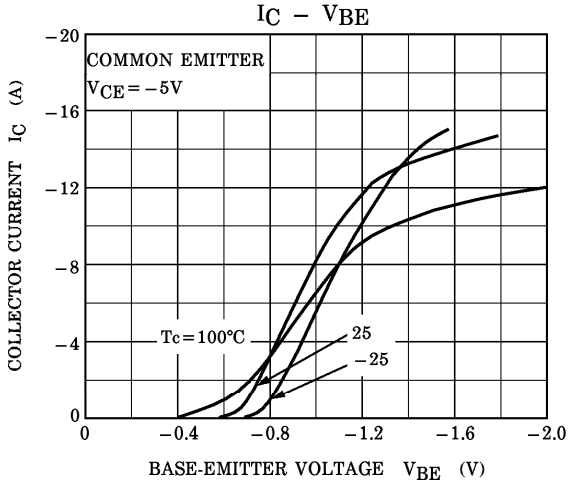
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -230V$, $I_E = 0$	—	—	−5.0	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5V$, $I_C = 0$	—	—	−5.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -50mA$, $I_B = 0$	−230	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE} = -5V$, $I_C = -1A$	55	—	160	
	$h_{FE(2)}$	$V_{CE} = -5V$, $I_C = -7A$	35	60	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -8A$, $I_B = -0.8A$	—	−1.5	−3.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -5V$, $I_C = -7A$	—	−1.0	−1.5	V
Transition Frequency	f_T	$V_{CE} = -5V$, $I_C = -1A$	—	30	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V$, $I_E = 0$, f = 1MHz	—	360	—	pF

Note : $h_{FE(1)}$ Classification R : 55~110, O : 80~160

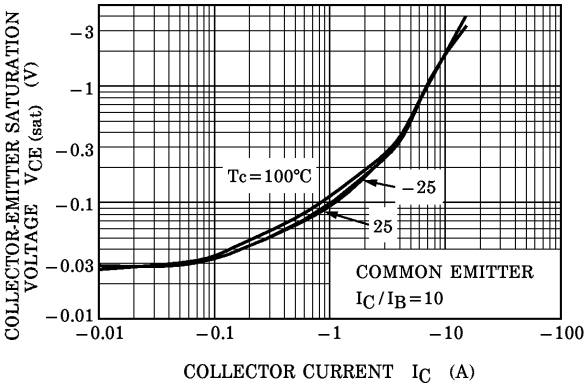
$I_C - V_{CE}$



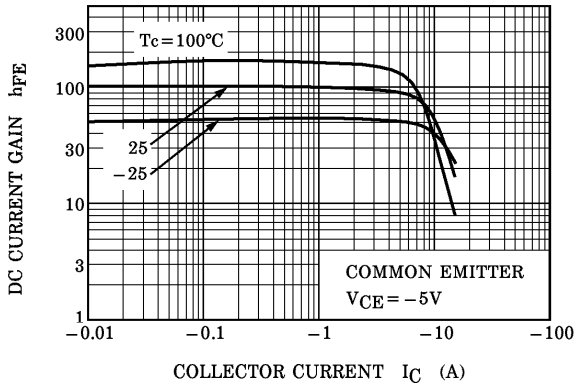
$I_C - V_{BE}$



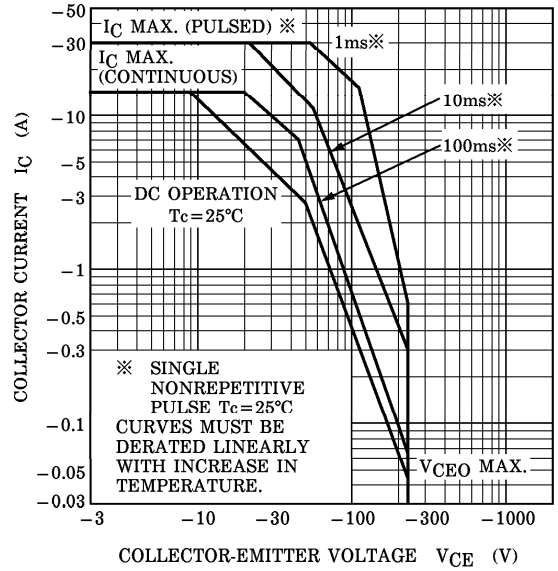
$V_{CE\,(sat)} - I_C$



$h_{FE} - I_C$



SAFE OPERATING AREA



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